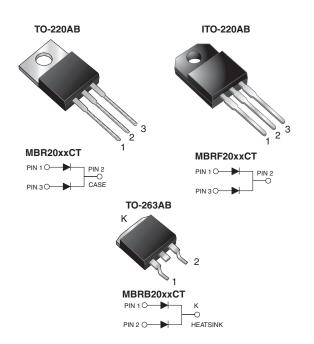
## MBR20xxCT, MBRF20xxCT, MBRB20xxCT

Vishay General Semiconductor

RoHS

## **Dual Common Cathode Schottky Rectifier**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
$V_{RRM}$	35 V to 60 V				
I <sub>FSM</sub>	150 A				
V <sub>F</sub>	0.57 V, 0.70 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Dual Common Cathode				

#### **FEATURES**

Power pack



- · Low power loss, high efficiency
- · Very low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER		MBR2035CT	MBR2045CT	MBR2050CT	MBR2060CT	UNIT	
Maximum repetitive peak reverse voltage		35	45	50	60		
Working peak reverse voltage	$V_{RWM}$	35	45	50	60	V	
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60		
Maximum average forward rectified current total device		20					
at T <sub>C</sub> = 135 °C per diode	I <sub>F(AV)</sub>	10					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	150				Α	
Peak repetitive reverse surge current per diode at $t_p = 2.0~\mu s$ , 1 kHz	I <sub>RRM</sub>	1.0 0.5		.5			
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000				V/µs	
Operating junction temperature range	TJ	- 65 to + 150				°C	
Storage temperature range	T <sub>STG</sub>	- 65 to + 175					
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500				V	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MBR2035CT	MBR2045CT	MBR2050CT	MBR2060CT	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	0.65		0.80			
		I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	0.57		0.70		V	
		$I_F = 20 \text{ A}$	T <sub>C</sub> = 25 °C	0.84		0.95			
		$I_F = 20 \text{ A}$	T <sub>C</sub> = 125 °C	0.	72	0.8	85		
Maximum reverse current at DC blocking voltage per diode	I <sub>R</sub> <sup>(2)</sup>	I <sub>R</sub> <sup>(2)</sup> Rated V <sub>R</sub>	T <sub>C</sub> = 25 °C	0	.1	0.	15	mA	
			T <sub>C</sub> = 125 °C	1	5	15	50	ША	

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical resistance from junction to case per diode	$R_{\theta JC}$	2.0	5.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2045CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2045CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2045CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2045CTHE3/45 1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2045CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

#### Note

(1) AEC-Q101 qualified

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#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

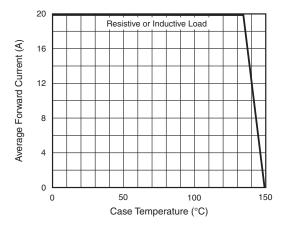


Fig. 1 - Forward Derating Curve (Total)

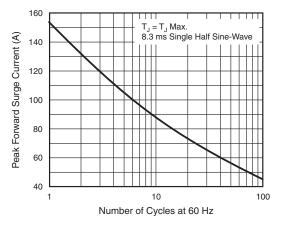


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

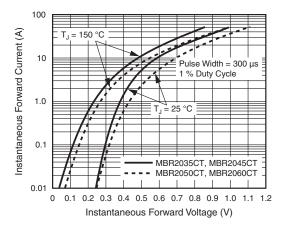


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

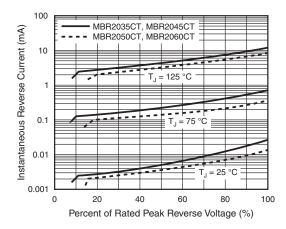


Fig. 4 - Typical Reverse Characteristics Per Diode

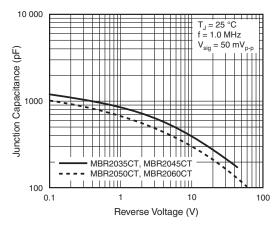


Fig. 5 - Typical Junction Capacitance Per Diode

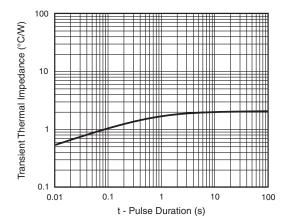


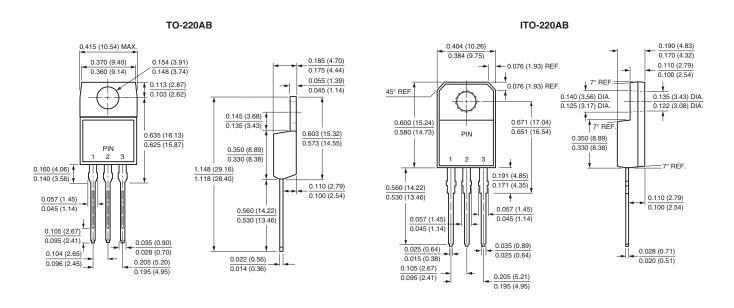
Fig. 6 - Typical Transient Thermal Impedance Per Diode

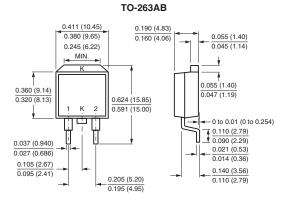


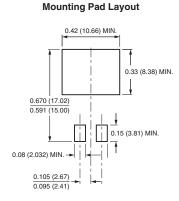
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#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)









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Revision: 13-Jun-16 1 Document Number: 91000